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RK7002A

## Transistors

# Switching (60V, 300mA)

## RK7002A

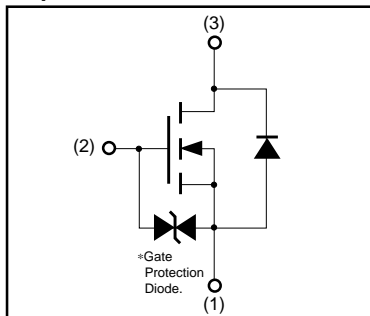
### ●Features

- 1) Low on-resistance.
- 2) High ESD
- 3) High-speed switching.
- 4) Low-voltage drive (4V).
- 5) Easily designed drive circuits.
- 6) Easy to use in parallel.

### ●Structure

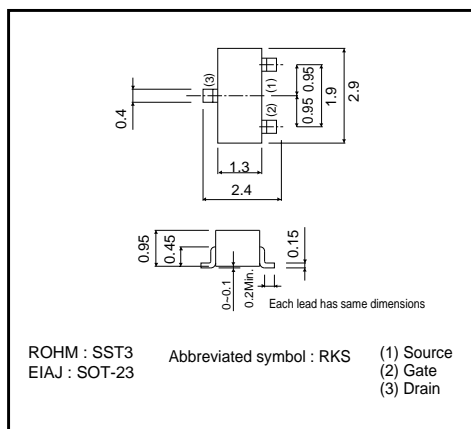
Silicon N-channel  
MOSFET transistor

### ●Equivalent circuit



\* A protection diode has been built in between the gate and the source to protect against static electricity when the product is in use.  
Use the protection circuit when fixed voltages are exceeded.

### ●External dimensions (Units : mm)



### ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-source voltage	$V_{DS}$	60	V
Gate-source voltage	$V_{GS}$	$\pm 20$	V
Drain current	Continuous	$I_D$	300 mA
	Pulsed	$I_{DP}^{*1}$	1.2 A
Drain reverse current	Continuous	$I_{DR}$	300 mA
	Pulsed	$I_{DRP}^{*1}$	1.2 A
Total power dissipation	$P_D^{*2}$	200	mW
Channel temperature	$T_{ch}$	150	°C
Storage temperature	$T_{stg}$	-55~+150	°C

\*1  $P_w \leq 10\mu s$ , Duty cycle  $\leq 1\%$

\*2 When using 1×0.75×0.062 inch glass epoxy board.

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#### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Gate leakage current	I <sub>GSS</sub>	—	—	±10	μA	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	60	—	—	V	I <sub>D</sub> =10μA, V <sub>GS</sub> =0V
Drain cutoff current	I <sub>DSS</sub>	—	—	1	μA	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS(th)</sub>	1	—	2.5	V	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA
Drain-source on-state resistance	R <sub>DS(on)</sub> *1	—	0.7	1.0	Ω	I <sub>D</sub> =300mA, V <sub>GS</sub> =10V
		—	1.1	1.5		I <sub>D</sub> =300mA, V <sub>GS</sub> =4V
Forward transfer admittance	Y <sub>fs</sub>  *1	200	—	—	mS	V <sub>DS</sub> =10V, I <sub>D</sub> =300mA
Input capacitance	C <sub>iss</sub>	—	33	—	pF	V <sub>DS</sub> =10V
Output capacitance	C <sub>oss</sub>	—	14	—	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	C <sub>rss</sub>	—	9	—	pF	f=1MHz
Turn-on delay time	t <sub>d(on)</sub> *2	—	6	—	ns	I <sub>D</sub> =150mA, V <sub>DD</sub> =30V
Rise time	t <sub>r</sub> *2	—	5	—	ns	V <sub>GS</sub> =10V
Turn-off delay time	t <sub>d(off)</sub> *2	—	13	—	ns	R <sub>L</sub> =200Ω
Fall time	t <sub>f</sub> *2	—	80	—	ns	R <sub>GS</sub> =10Ω
Total gate charge	Q <sub>g</sub> *2	—	3	6	nC	V <sub>DD</sub> =30V
Gate-source charge	Q <sub>gs</sub> *2	—	0.6	—	nC	V <sub>GS</sub> =10V
Gate-drain charge	Q <sub>gd</sub> *2	—	0.5	—	nC	I <sub>D</sub> =200mA

\*1 P<sub>W</sub>≤300μs, Duty cycle≤1%

\*2 Pulsed

#### ●Packaging specifications

Type	Package	Taping
	Code	T116
	Basic ordering unit (pieces)	3000
RK7002A		○

#### ●Electrical characteristic curves

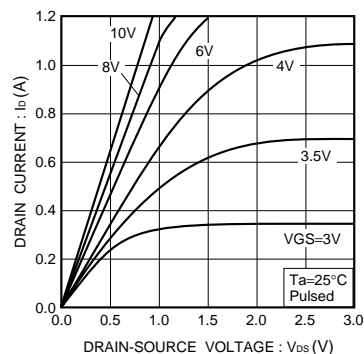


Fig.1 Typical output characteristics

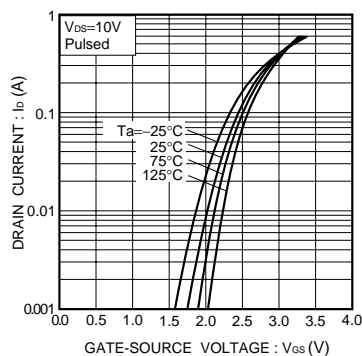


Fig.2 Typical transfer characteristics

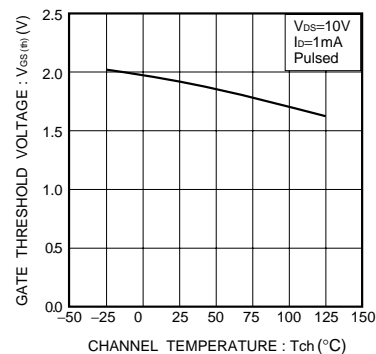


Fig.3 Gate threshold voltage vs. channel temperature

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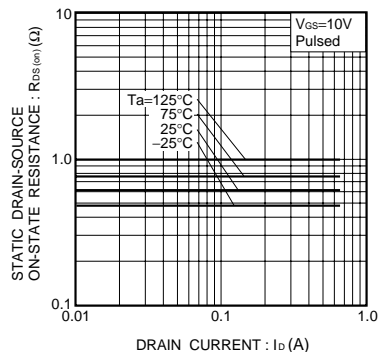


Fig.4 Static drain-source on-state resistance vs. drain current ( I )

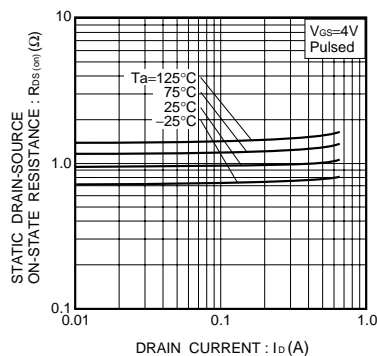


Fig.5 Static drain-source on-state resistance vs. drain current ( II )

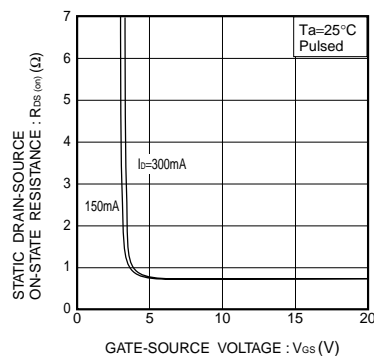


Fig.6 Static drain-source on-state resistance vs. gate-source voltage

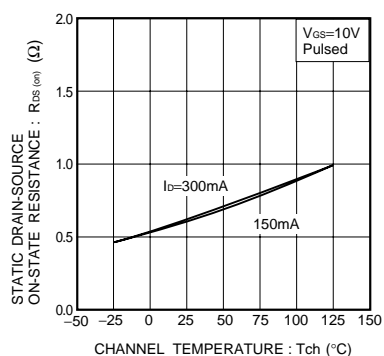


Fig.7 Static drain-source on-state resistance vs. channel temperature

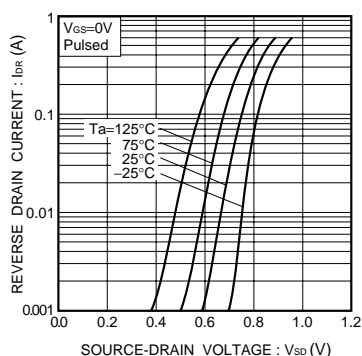


Fig.8 Reverse drain current vs. source-drain voltage ( I )

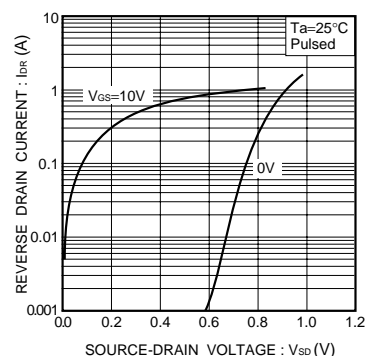


Fig.9 Reverse drain current vs. source-drain voltage ( II )

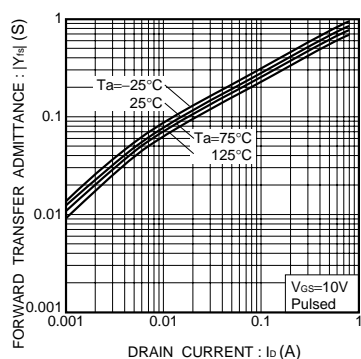


Fig.10 Forward transfer admittance vs. drain current

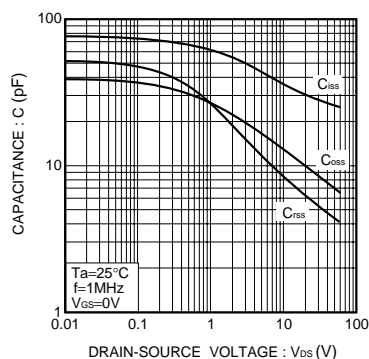


Fig.11 Typical capacitance vs. drain-source voltage

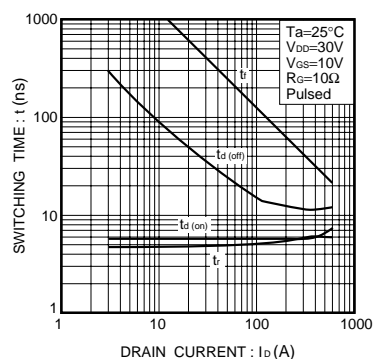


Fig.12 Switching characteristics (See Figures 13 and 14 for the measurement circuit and resultant waveforms)

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### ●Switching characteristics measurement circuit

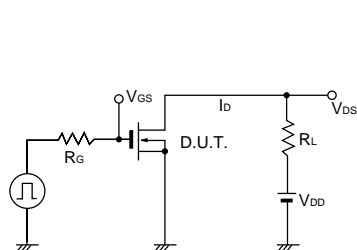


Fig.13 Switching time measurement circuit

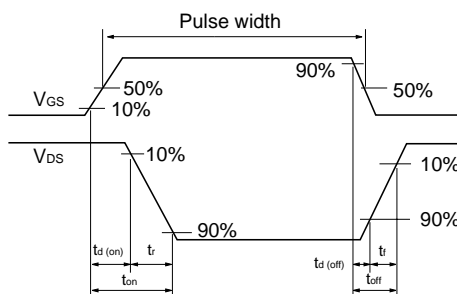


Fig.14 Switching time waveforms

## Appendix

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